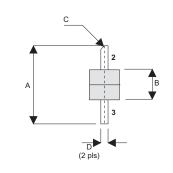
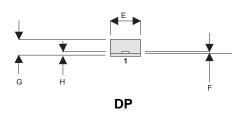


ROHS COMPLIANT METAL GATE RF SILICON FET

MECHANICAL DATA





PIN 1 SOURCE PIN₂ DRAIN

PIN₃ **GATE**

DIM	mm	Tol.	Inches	Tol.
Α	16.51	0.25	0.650	0.010
В	6.35	0.13	0.250	0.005
С	45°	5°	45°	5°
D	1.52	0.13	0.060	0.005
Е	6.35	0.13	0.250	0.005
F	0.13	0.03	0.005	0.001
G	3.56	0.51	0.140	0.020
Н	0.64	0.13	0.024	0.005

GOLD METALLISED MULTI-PURPOSE SILICON DMOS RF FET 10W - 12.5V - 1GHz SINGLE ENDED

FEATURES

- SIMPLIFIED AMPLIFIER DESIGN
- SUITABLE FOR BROAD BAND APPLICATIONS
- LOW C_{rss}
- SIMPLE BIAS CIRCUITS
- LOW NOISE
- HIGH GAIN 10 dB MINIMUM

APPLICATIONS

 VHF/UHF COMMUNICATIONS from DC to 1 GHz

ABSOLUTE MAXIMUM RATINGS (T_{case} = 25℃ unless otherwise stated)

$\overline{P_D}$	Power Dissipation	42W
BV_DSS	Drain – Source Breakdown Voltage	40V
BV_GSS	Gate – Source Breakdown Voltage	±20V
I _{D(sat)}	Drain Current	8A
T _{stg}	Storage Temperature	–65 to 150℃
Tj	Maximum Operating Junction Temperature	200℃

Semelab PIc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

E-mail: sales@semelab.co.uk

Semelab plc. Telephone +44(0)1455 556565. Fax +44(0)1455 552612.

Website: http://www.semelab.co.uk

Document Number: 3042

Issue: 3



ELECTRICAL CHARACTERISTICS (T_{case} = 25°C unless otherwise stated)

Parameter		Test Conditions			Min.	Тур.	Max.	Unit
B\/	Drain-Source	V _{GS} = 0	I 10m	۰,۸	40			V
BV _{DSS}	Breakdown Voltage	VGS = 0	I _D = 10mA		40			V
,	Zero Gate Voltage	\/ _ 12.5\/	· · · · · · · · · · · · · · · · · · ·				1	- A
IDSS	Drain Current	$V_{DS} = 12.5V$	$V_{GS} = 0$				ı	mA
I _{GSS}	Gate Leakage Current	V _{GS} = 20V	V _{DS} = 0				1	μА
V _{GS(th)}	Gate Threshold Voltage*	I _D = 10mA	V _{DS} = V	GS	0.5		7	V
9 _{fs}	Forward Transconductance*	V _{DS} = 10V	I _D = 0.8	4	0.72			S
G _{PS}	Common Source Power Gain	P _O = 10W			10			dB
η	Drain Efficiency	V _{DS} = 12.5V	$I_{DQ} = 0.4$	4A	40			%
VSWR	Load Mismatch Tolerance	f = 1GHz			20:1			_
C _{iss}	Input Capacitance	$V_{DS} = 0$	$V_{GS} = -5V f =$	1MHz			48	pF
C _{oss}	Output Capacitance	V _{DS} = 12.5V	$V_{GS} = 0$ f =	1MHz			40	pF
C _{rss}	Reverse Transfer Capacitance	$V_{DS} = 12.5V$	$V_{GS} = 0$ f =	1MHz			4	pF

^{*} Pulse Test: Pulse Duration = 300 μs , Duty Cycle $\leq 2\%$

HAZARDOUS MATERIAL WARNING

The ceramic portion of the device between leads and metal flange is beryllium oxide. Beryllium oxide dust is highly toxic and care must be taken during handling and mounting to avoid damage to this area.

THESE DEVICES MUST NEVER BE THROWN AWAY WITH GENERAL INDUSTRIAL OR DOMESTIC WASTE.

THERMAL DATA

R _{THj} -case Thermal Resistance Junction – Case Max.	1.2℃ / W
--	----------

Semelab PIc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

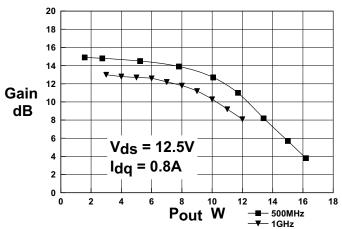
E-mail: sales@semelab.co.uk

Semelab plc. Telephone +44(0)1455 556565. Fax +44(0)1455 552612. Website: http://www.semelab.co.uk

Document Number: 3042

Issue: 3





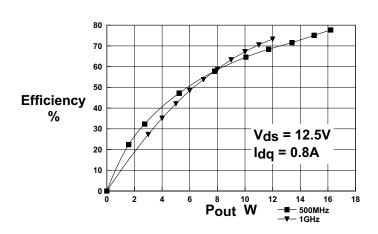
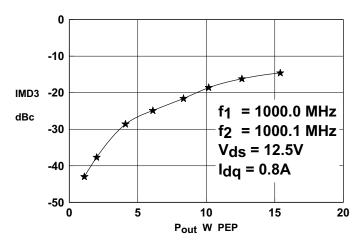


Figure 1- Gain vs. Power Output

Figure 2 - Efficiency vs Output Power



D2214UK OPTIMUM SOURCE AND LOAD IMPEDANCE

Frequency MHz	Z _S Ω	Z_{L}		
1000MHz	0.9 – j4.9	1.9 – j7.3		

Figure 3 - IMD vs Power Output

Typical S Parameters

 $V_{DS} = 12.5V, I_{DQ} = 0.8A$

MHZ S MA R 50

!Freq !MHz	S11 mag	ang	S21 mag	ang	S12 mag	ang	S22 mag	ang
70 100 150 200 250 300 350 400 450 500 550 600 650	mag 0.77 0.75 0.77 0.80 0.83 0.85 0.87 0.88 0.90 0.90 0.92 0.92 0.93	ang -124.6 -136.7 -148 -154.9 -160.2 -164.1 -167.8 -170.9 -174.5 -177.5 179.2 176.5 174.6	mag 19.6 14.7 9.3 6.4 4.7 3.8 3.0 2.5 2.0 1.8 1.5 1.4	ang 100.6 89.0 72.2 61.7 52.8 49.3 39.7 39.0 33.8 31.5 25.5 20.4 17.5	mag 0.020 0.020 0.017 0.015 0.012 0.010 0.007 0.006 0.007 0.009 0.012 0.016 0.018	ang 10.0 2.0 -7.6 -10.3 -10.4 -4.1 8.7 29.4 56.1 73.1 80.5 81.4 84.5	0.58 0.60 0.65 0.71 0.76 0.79 0.82 0.85 0.87 0.87 0.90 0.90	-120.3 -130.3 -140.3 -146.8 -151.4 -155.5 -152.6 -162.6 -165.9 -168.5 -171.7 -174.4 -176.5
700 750 800 850 900 950 1000	0.94 0.94 0.95 0.95 0.96 0.96	172.2 169.7 167.6 165.5 164.1 161.3 158.6	1.1 0.9 0.7 0.6 0.6 0.6	11.7 10.0 7.7 11.4 11.4 12.3 8.7	0.021 0.022 0.024 0.027 0.031 0.036 0.040	81.5 83.0 82.7 88.1 89.0 89.5 86.0	0.92 0.93 0.94 0.94 0.95 0.95	-178.7 179.1 177.2 174.4 172.6 170.6

Semelab PIc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

Semelab plc. Telephone +44(0)1455 556565. Fax +44(0)1455 552612. Document Number: 3042 Issue: 3

E-mail: sales@semelab.co.uk

Website: http://www.semelab.co.uk





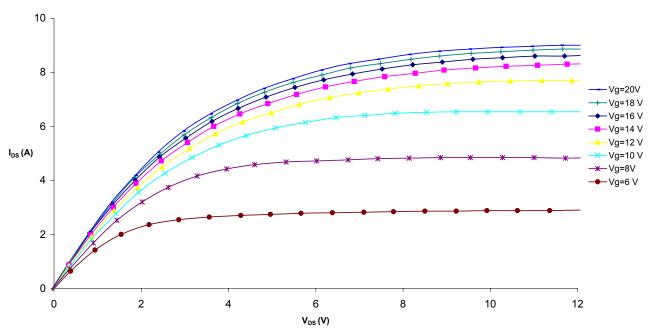


Figure 4 – Typical IV Characteristics.

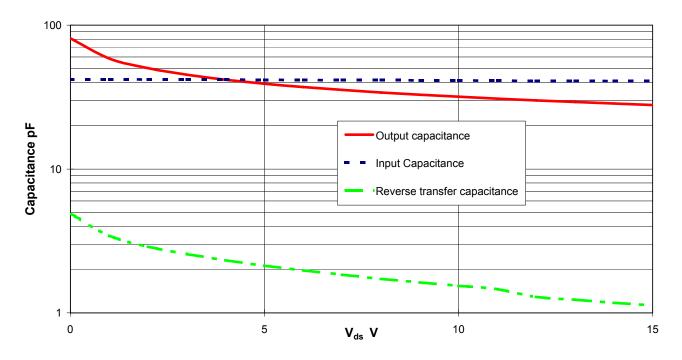


Figure 5 – Typical CV Characteristics.

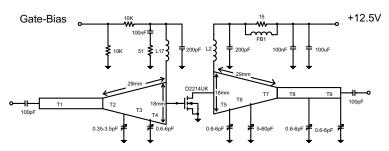
Semelab Plc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

Semelab plc. Telephone +44(0)1455 556565. Fax +44(0)1455 552612. Document Number: 3042

E-mail: sales@semelab.co.uk Website: http://www.semelab.co.uk Issue: 3



Issue: 3



Substrate 0.8mm PTFE/glass

T1 28mm 50 Ohms T6 14mm
T2 11mm T7 10mm

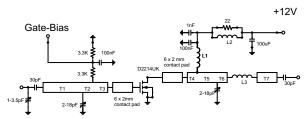
T3 11mm T8 11mm 50 Ohms T4 7mm T9 17mm 50 Ohms

T5 5mm

FB1 Murata BL02RN1-R62

L1,L2 10 turns 22swg enamelled copper wire, 6mm i.d.

Figure 6 - 1GHz Test Fixture



Substrate 0.8mm PTFE/glass, Er=2.5

All microstrip lines W=2.2mm

T1 32mm

T2 4mm

T3 5mm

T4 3mm T5 9mm

T6 7.5mm

T7 13mm

L1 6 turns 0.5mm dia enamelled copper wire, 3mm i.d.

L2 1.5 turns 0.5mm enamelled copper wire on Siemens B62152A7 2 hole ferrite core

L3 1/16" dia wire hairpin loop 15mm long

Figure 7 - 500MHz Test Fixture

Semelab Plc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

Semelab plc. Telephone +44(0)1455 556565. Fax +44(0)1455 552612. Document Number: 3042

E-mail: sales@semelab.co.uk Website: http://www.semelab.co.uk